Vishay Siliconix

DG3157

High-Speed, Low R_{ON}, SPDT Analog Switch

(2:1 Multiplexer/Demultiplexer Bus Switch)

DESCRIPTION

The DG3157 is a high-speed single-pole double-throw, low power, TTL-Compatible bus switch. Using sub-micro CMOS technology, the DG3157 achieves low on-resistance and negligible propagation delay.

The DG3157 can handle both analog and digital signals and permits signals with amplitudes of up to V_{CC} to be transmitted in either direction.

When the Select pin is low, B₀ is connected to the output A pin. When the Select pin is high, B1 is connected to the output A pin. The path that is open will have a highimpedance state with respect to the output. Make-beforebreak is guaranteed. An eptiaxial layer prevents latch-up.

FEATURES

- Halogen-free According to IEC 61249-2-21
- Direct cross to industry standard SN74LVC1G3157, NC7SB3157, NLASB3175, PI5A3157, and STG3157
- SC-70 6-lead package
- 1.65 V to 5.5 V V_{CC} operation
- 5 Ω connection between ports
- Minimal propagation delay
- Break-before-make switching
- Zero bounce in flow-through mode

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



ORDERING INFORMATION						
Temp. Range	Package	Part Number				
- 40 °C to 85 °C	SC-70-6	DG3157DL-T1-E3 DG3157DL-T1-GE3 (Halogen-free)				



Device Marking: G1



RoHS

COMPLIANT

HALOGEN

FREE





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ABSOLUTE MAXIMUM RATINGS						
Parameter	Limit	Unit				
Reference V+ to GND	- 0.3 to + 6					
S, A, B ^a	- 0.3 to (V+ + 0.3)	- V				
Continuous Current (Any terminal)	± 50	mA				
Peak Current (Pulsed at 1 ms, 10 % duty cy	± 200	— mA				
Storage Temperature	D Suffix	- 65 to 150	°C			
Power Dissipation (Packages) ^b	6-Pin SC-70 ^c	250	mW			

Notes:

a. Signals on A, or B or S exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 3.1 mW/°C above 70 °C.

		Test ConditionsUnless Otherwise SpecifiedV+ = 3.0 V, V _S = 0.25 V to 0.7 V+ ^e			Limits - 40 °C to 85 °C			
Parameter	Symbol			Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit
DC Characteristics								
High Level Input Voltage	V _{SH}	V+ = 1.65 to 1.95 V		Full	0.75 V+			
riigh Level input voltage	• 5H	V+ = 2.3 to 5.5 V		Full	0.7 V+			v
Low Level Input Voltage	V _{SL}		V+ = 1.65 to 1.95 V				0.25 V+	v
Low Level input voltage	•SL	V+	= 2.3 to 5.5 V	Full			0.3 V+	
			V _{BN} = 0 V, I _A = 30 mA	Full		6	7	-
		V+ = 4.5 V	V _{BN} = 2.3 V, I _A = - 30 mA	Full		6	12	
			V _{BN} = 4.5 V, I _A = - 30 mA	Full		9	15	
		V+ = 3.0 V	V _{BN} = 0 V, I _A = 24 mA	Full		8	9	
On Resistance	R _{ON}	V+ = 3.0 V	V _{BN} = 3.0 V, I _A = - 24 mA	Full		12	20	
		V+ = 2.3 V	V _{BN} = 0 V, I _A = 8 mA	Full		9	12	Ω
		V+=2.3 V	V _{BN} = 2.3 V, I _A = - 8 mA	Full		13	30	
		V+ = 1.65 V	$V_{BN} = 0 V, I_A = 4 mA$	Full		12	20	
			V _{BN} = 1.8 V, I _A = - 4 mA	Full		18	50	
	R _{FLAT}	0 < V _{BN} < V+	V+ = 4.5 V, I _A = - 30 mA	Room		6		
			V+ = 3.0 V, I _A = - 24 mA	Room		12		
On Resistance Flatness			V+ = 2.3 V, I _A = - 8 mA	Room		22		
			V+ = 1.65 V, I _A = - 4 mA	Room		90		
	ΔR _{ON}	V+ = 4.5 V, V _{BN} = 3.15 V, I _A = - 30 mA		Room		0.32		
On Resistance Matching		V+ = 3.0 V, V _{BN} = 2.1 V, I _A = - 24 mA		Room		0.31		
Between Channels		$V_{+} = 2.3 V, V_{BN} = 1.6 V, I_{A} = -8 mA$		Room		0.30		
		V+ = 1.65 V, V _{BN} = 1.15 V, I _A = - 4 mA		Room		0.29		
Input Leakage Current	۱ _S	$V_{+} = 5.5 V, V_{A} = 5.5 V$		Room Full	- 0.1 - 1.0		0.1 - 1.0	
Off Stage Switch Leakage	I _{BN(off)}	V+ = 5.5 V, $V_A/V_B = 0$ V/5.5 V		Room Full	- 0.1 - 1.0		0.1 - 1.0	μA
On State Switch Leakage	I _{BN(on)}	V+ = 5.5 V, $V_A/V_B = 0 V/5.5 V$		Room Full	- 0.1 - 1.0		0.1 - 1.0	



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SPECIFICATIONS	- 1	Test Con	ditiono	1	1	Limite		
		Unless Otherw		Limits - 40 °C to 85 °C				
Parameter	Symbol	V+ = 3.0 V, V _S = 0	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit	
Power Supply		<u> </u>		<u> </u>				
Power Supply Range	V+			Full	1.65		5.5	V
Quiescent Supply Current	l+	V+ = 5.5 V, V _A = V	/ _B = V+ or GND	Room			1	μA
AC Electrical Characteristice		· A		Full			10	
AC Electrical Characteristice			V+ = 1.65 to 1.95 V	Full		1	[]	
			V = 1.65 to 1.95 V V+ = 2.3 to 2.7 V	Full		1.2		
Prop Delay Time ^f	t _{PHL} /t _{PLH}	$V_A = 0 V$	V + = 2.3 to 2.7 V V+ = 3.0 to 3.6 V	Full		0.8		
			V = 3.0 to 3.0 V V+ = 4.5 to 5.5 V	Full		0.8		
			V+ = 4.5 to 5.5 V	Room		10.2		
			V+ = 1.65 to 1.95 V	Full		10.2		
			N/ 0.0 to 0.7 V/	Room		5.9		- - - - -
	t _{PZL} /t _{PZH}	$V_{LOAD} = 2 \times V + \text{ for } t_{PZL}$	V+ = 2.3 to 2.7 V	Full		6.2		
Output Enable Time ^f	'PZL/'PZH	$V_{LOAD} = 0 V$ for t_{PZH}	V+ = 3.0 to 3.6 V V+ = 4.5 to 5.5 V	Room		4.1		
				Full		4.5		
				Room		2.6		
f		$V_{LOAD} = 2 \times V_{+}$ for t_{PLZ} $V_{LOAD} = 0 V$ for t_{PHZ}	V+ = 1.65 to 1.95 V V+ = 2.3 to 2.7 V	Full Room		2.9 10.2		
				Full		10.2		
				Room		5.9		
	t _{PLZ} /t _{PHZ}			Full		6.2		
Output Disable Time ^f	^I PLZ ^{/I} PHZ		V+ = 3.0 to 3.6 V	Room		4.1		
			V + = 3.0 to 3.6 V	Full		4.5		
			V+ = 4.5 to 5.5 V	Room		2.6		
				Full		2.9		-
		V+ = 1.65 to 1.95 V		Full	0.5			
Break-Before-Make Time ^d	t _{BBM}	V+ = 2.3 to 2.7 V		Full	0.5			
		V+ = 3.0 to 3.65		Full	0.5			
		V+ = 4.5 t		Full	0.5			┝───
Charge Injection ^d	Q	$C_{L} = 0.1 \text{ nF}, V_{GEN} = 0 \text{ V}$		Room		7		pC
•		$R_{GEN} = 0 \Omega$	V+ = 3.3 V	Room		3		<u> </u>
Analog Switch Characteristic	s OIRR			Room		- 57.6		
Off Isolation ^d	-	R _L = 50 Ω, f	= 10 MHz	Room		- 57.6		dB
Crosstalk ^d	X _{TALK}	R _L = 50 Ω						N 41 1-
- 3 db Bandwidth ^d	BW	R _L = c		Room		> 250		MHz
Capacitance Control Pin Capacitance ^d	C _{IN}	V+ =	0.V	Room		4.9		
		v+=	U V			-		
B Port Off Capacitance ^d	C _{IO-B}	V+ =	5 V	Room		< 6.5		pF
A Port Capacitance When Switch Enable ^d	C _{IO-A(on)}	V+ =	5 V	Room		< 18.5		
otes:								I

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

c. Typical values are for design aid only, not guaranteed nor subject to production testing.

d. Guarantee by design, nor subjected to production test.

e. V_{IN} = input voltage to perform proper function.

f. Guaranteed by design and not production tested. The bus switch propagation delay is a function of the RC time constant contributed by the on-resistance and the specified load capacitance with an ideal voltage source (zero output impedance) driving the switch.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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LOGIC DIAGRAM Positive Logic





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





AC LOADING AND WAVEFORMS



Figure 2. AC Test Circuit



Propagation Delay Times

Enable and Disable Time-Low- and High-Level Enabling



Notes:

- C_L includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
- The outputs are measured one at a time with one transition per measurement.
- \bullet t_{PLZ} and t_{PHZ} are the same as $t_{dis}.$
- \bullet t_{PZL} and t_{PZH} are the same as $t_{\text{dis}}.$
- \bullet t_{PLH} and t_{PHL} are the same as $t_{dis}.$
- V_{LD} = 2 V+.

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TEST CIRCUITS





CL (includes fixture and stray capacitance)

Figure 4. Break-Before-Make Interval





IN depends on switch configuration: input polarity determined by sense of switch.









Figure 7. Channel Off/On Capacitance

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Package Information Vishay Siliconix

SC-70: 6-LEADS





	MIL	LIMET	ERS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.90	-	1.10	0.035	-	0.043	
A ₁	-	-	0.10	-	-	0.004	
A ₂	0.80	-	1.00	0.031	-	0.039	
b	0.15	-	0.30	0.006	-	0.012	
С	0.10	-	0.25	0.004	-	0.010	
D	1.80	2.00	2.20	0.071	0.079	0.087	
Е	1.80	2.10	2.40 0.071		0.083	0.094	
E ₁	1.15	1.25	1.35	0.045	0.049	0.053	
е		0.65BSC			0.026BSC	;	
e ₁	1.20	1.30	1.40	0.047	0.051	0.055	
L	0.10	0.20	0.30	0.004	0.008	0.012	
٩		7°Nom		7°Nom			
ECN: S-03946—Rev. B, 09-Jul-01 DWG: 5550							



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